# 2SD2158, 2SD2158A

### Silicon NPN triple diffusion planar type

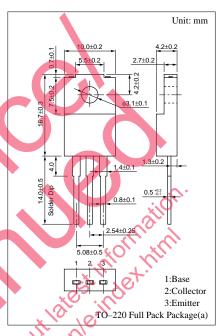
For power amplification with high forward current transfer ratio

#### Features

- High foward current transfer ratio h<sub>FE</sub>
- Satisfactory linearity of foward current transfer ratio h<sub>FE</sub>
- Full-pack package which can be installed to the heat sink with one screw

#### Absolute Maximum Ratings (T<sub>C</sub>=25°C)

Parameter		Symbol	Ratings	Unit	
Collector to	2SD2158	V	80	v	
base voltage	2SD2158A	$V_{CBO}$	100	V	
Collector to	2SD2158	3.7	60	77	
emitter voltage	2SD2158A	$V_{CEO}$	80	Y	
Emitter to base voltage		$V_{EBO}$	6	V	
Peak collector current		$I_{CP}$	4	A	
Collector current		$I_{C}$	2	A	
Base current		$I_B$	0.5	A	
Collector power	T <sub>C</sub> =25°C		20	W	
dissipation	Ta=25°C	$P_{C}$	2	W	
Junction temperature		$T_{j}$	150	°C	
Storage temperature		T <sub>stg</sub>	-55 to +150	°C	



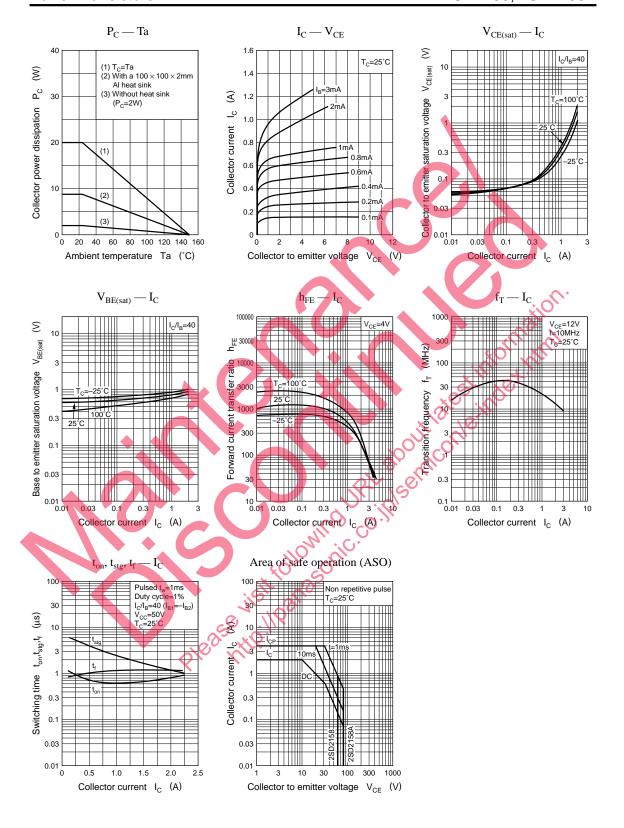
#### Electrical Characteristics (T<sub>C</sub>=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff 2SD2158		$V_{CB} = 80V, I_E = 0$			100	
current 2SD2158A	СВО	$V_{CB} = 100V, I_{E} = 0$			100	μΑ
Collector cutoff current	$I_{CEO}$	$V_{CE} = 40V, I_B = 0$			100	μΑ
Emitter cutoff current	$I_{EBO}$	$V_{\rm EB} = 6V$ , $I_{\rm C} = 0$			100	μΑ
Collector to emitter 2SD2158	V - 6	$I_{C}=25\text{mA}, I_{B}=0$	60			
voltage 2SD2158A	V <sub>CEO</sub>		80			V
Forward current transfer ratio	h <sub>FE</sub> *	$V_{CE} = 4V, I_{C} = 300mA$	500		2500	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 1A, I_B = 25mA$			1	V
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	$I_C = 1A, I_B = 25mA$			1.2	V
Transition frequency	$f_T$	$V_{CE} = 12V, I_{C} = 200mA, f = 10MHz$		40		MHz
Collector output capacitance	C <sub>ob</sub>	$V_{CB} = 10V, I_E = 0, f = 1MHz$		30		pF
Turn-on time	t <sub>on</sub>	I - 1 A I - 25 m A I - 25 m A		0.6		μs
Storage time	t <sub>stg</sub>	$I_C = 1A$ , $I_{B1} = 25mA$ , $I_{B2} = -25mA$ ,		2.5		μs
Fall time	t <sub>f</sub>	$V_{CC} = 50V$		1		μs

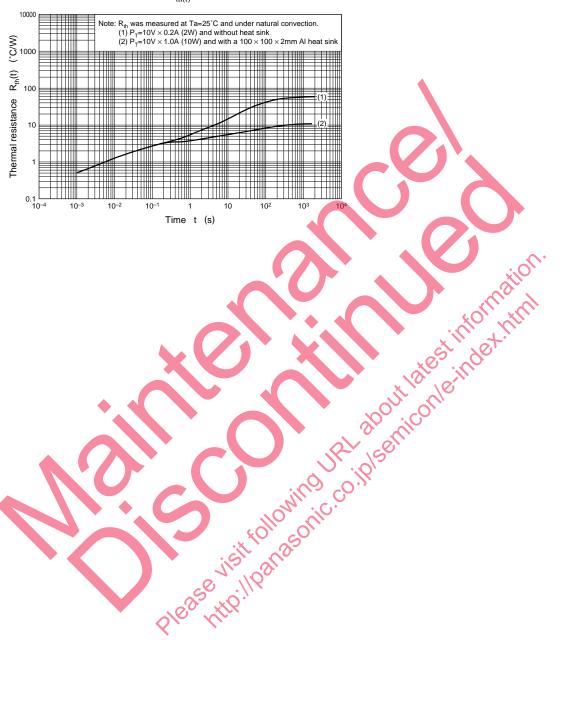
#### \*h<sub>FE</sub> Rank classification

Rank	Q	P	О	
h <sub>FE</sub>	500 to 1000	800 to 1500	1200 to 2500	

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